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1 Electrical ratings

Table 2. Absolute maximum ratings

		Value	e	
Symbol	Parameter	TO-220/I ² PAK D ² PAK / DPAK	TO-220FP	Unit
V_{DS}	Drain-source voltage (V _{GS} = 0)	500		V
V _{GS}	Gate-source voltage	± 25		V
I_D	Drain current (continuous) at T _C = 25 °C	11	11 ⁽¹⁾	Α
I _D	Drain current (continuous) at T _C =100 °C	6.7	6.7 ⁽¹⁾	А
I _{DM} ⁽²⁾	Drain current (pulsed)	44	44 (1)	Α
P _{TOT}	Total dissipation at T _C = 25 °C	100	25	W
dv/dt ⁽³⁾	Peak diode recovery voltage slope	15		V/ns
V _{ISO}	Insulation withstand voltage (RMS) from all three leads to external heat sink (t=1 s; T_C =25 $^{\circ}C$)	3	2500	٧
T _{stg}	Storage temperature	-55 to 1	50	°C
T_J	Max. operating junction temperature	150		°C

- Limited only by maximum temperature allowed
- 2. Pulse width limited by safe operating area
- 3. $I_{SD} \leq 11A$, di/dt $\leq 400A/\mu s$, $V_{DD} = 80\%V_{(BR)DSS}$

Table 3. Thermal data

	Symbol	nbol Parameter		Value				
	Symbol	Parameter	TO-220	I ² PAK	DPAK	D ² PAK	TO-220FP	Unit
\ C	R _{thj-case}	Thermal resistance junction- case max		1.2	25		5	°C/W
1050le	R _{thj-amb}	Thermal resistance junction-amb max	62.	5			62.5	°C/W
Op	R _{thj-pcb}	Thermal resistance junction-pcb max			50	30		°C/W
	T _I	Maximum lead temperature for soldering purposes			300			°C

Table 4. Avalanche characteristics

Symbol	Parameter	Value	Unit
I _{AS}	Avalanche current, repetitive or not-repetitive (pulse width limited by Tj Max)	5	Α
E _{AS}	Single pulse avalanche energy (starting Tj=25°C, Id=las, Vdd=50V)	350	mJ

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2 Electrical characteristics

(T_{CASE}=25 °C unless otherwise specified)

Table 5. On/off states

Symbol	Parameter	Test conditions	Min	Тур.	Max	Unit
V _{(BR)DSS}	Drain-source breakdown voltage	$I_D = 1 \text{ mA}, V_{GS} = 0$	500			V
dv/dt ⁽¹⁾	Peak diode recovery voltage slope	V _{DD} =400 V, I _D =11 A, V _{GS} =10 V		44	4	V/ns
I _{DSS}	Zero gate voltage drain current (V _{GS} = 0)	V_{DS} = max rating, V_{DS} = max rating@125 °C		(1 100	μA μA
I _{GSS}	Gate body leakage current (V _{DS} = 0)	V _{GS} = ±20 V	, (O	0.0	100	nA
V _{GS(th)}	Gate threshold voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2	3	4	٧
R _{DS(on)}	Static drain-source on resistance	V _{GS} = 10 V, I _D = 5.5 A		0.29	0.38	Ω

^{1.} Characteristic value at turn off inductive load

Table 6. Dynamic

	Symbol	Parameter	Test conditions	Min	Тур.	Max	Unit
	g _{fs} ⁽¹⁾	Forward transconductance	$V_{DS} = 15 \text{ V}, I_D = 5.5 \text{ A}$		8		S
	C _{iss} C _{oss} C _{rss}	Input capacitance Output capacitance Reverse transfer capacitance	V _{DS} =50 V, f=1 MHz, V _{GS} =0		940 100 10		pF pF pF
7/6	C _{oss eq} ⁽²⁾	Equivalent output capacitance	V _{GS} =0, V _{DS} =0 to 400 V		130		pF
Opso	Q _g Q _{gs} Q _{gd}	Total gate charge Gate-source charge Gate-drain charge	V_{DD} =400 V, I_{D} = 11 A V_{GS} =10 V (see Figure 17)		30 6 15		nC nC nC
	R_{g}	Gate input resistance	f=1 MHz Gate DC Bias=0 test signal level=20 mV open drain		4.5		Ω

^{1.} Pulsed: pulse duration=300 μs , duty cycle 1.5%

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^{2.} $C_{oss\,eq.}$ is defined as a constant equivalent capacitance giving the same charging time as C_{oss} when V_{DS} increases from 0 to 80% V_{DSS}

Table 7. Switching times

Symbol	Parameter	Test conditions	Min	Тур.	Max	Unit
$t_{d(on)}$ t_{r} $t_{d(off)}$ t_{f}	Turn-on delay time Rise time Turn-off delay time Fall time	V_{DD} =250 V, I_D = 5.5 A, R_G =4.7 Ω , V_{GS} =10 V (see Figure 16)		15 15 60 14		ns ns ns ns

Table 8. Source drain diode

Symbol	Parameter	Test conditions	Min	Тур.	Max	Unit
I _{SD}	Source-drain current				11	Α
I _{SDM} ⁽¹⁾	Source-drain current (pulsed)			411	44	Α
V _{SD} ⁽²⁾	Forward on voltage	I _{SD} =11 A, V _{GS} =0	C	0	1.3	V
t _{rr} Q _{rr} I _{RRM}	Reverse recovery time Reverse recovery charge Reverse recovery current	I _{SD} =11 A, V _{DD} =100 V di/dt = 100 A/µs, (see Figure 18)		340 3.5 20		ns μC A
t _{rr} Q _{rr} I _{RRM}	Reverse recovery time Reverse recovery charge Reverse recovery current	I_{SD} =11 A, di/dt = 100 A/ μ s, V_{DD} =100 V, Tj=150 °C (see Figure 18)		420 4 20		ns μC A

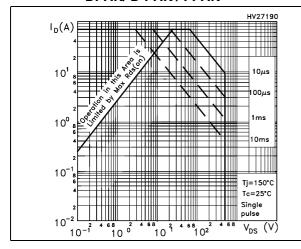
^{1.} Pulse width limited by safe operating area

^{2.} Pulsed: pulse duration=300 µs, duty cycle 1.5%

2.1 Electrical characteristics (curves)

Figure 2. Safe operating area for TO-220/ DPAK/ D²PAK / I²PAK

Figure 3. Thermal impedance for TO-220/ DPAK/ D²PAK / I²PAK



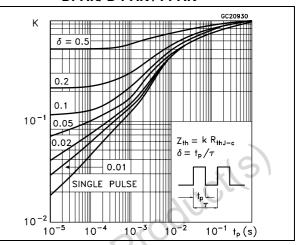
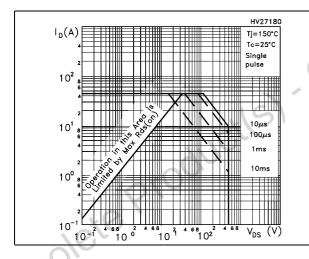


Figure 4. Safe operating area for TO-220FP

Figure 5. Thermal impedance for TO-220FP



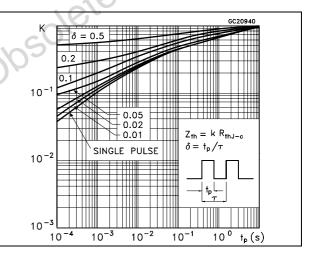
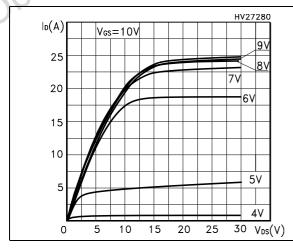


Figure 6. Output characteristics

Figure 7. Transfer characteristics



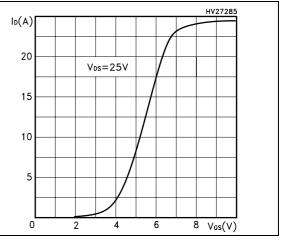


Figure 8. Transconductance

Figure 9. Static drain-source on resistance

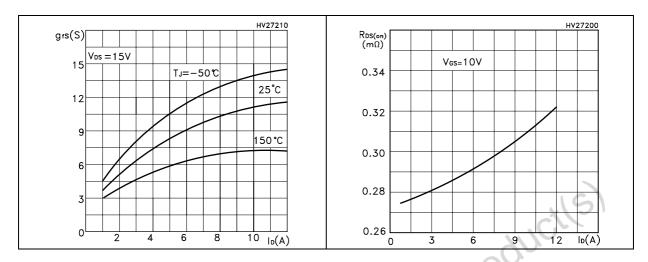


Figure 10. Gate charge vs gate-source voltage Figure 11. Capacitance variations

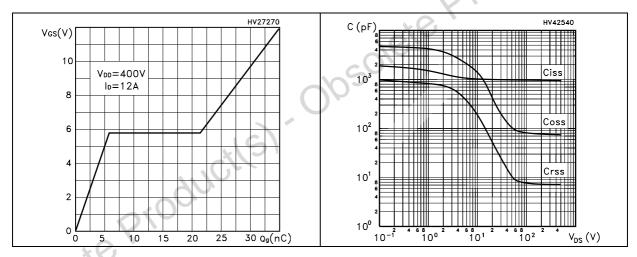


Figure 12. Normalized gate threshold voltage Figure 13. Normalized on resistance vs vs temperature temperature

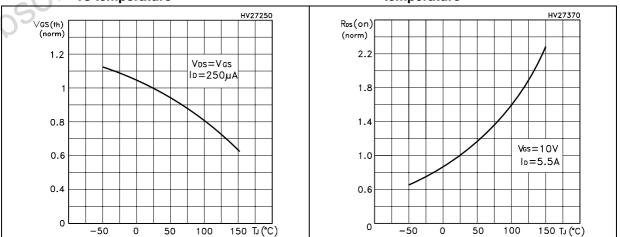
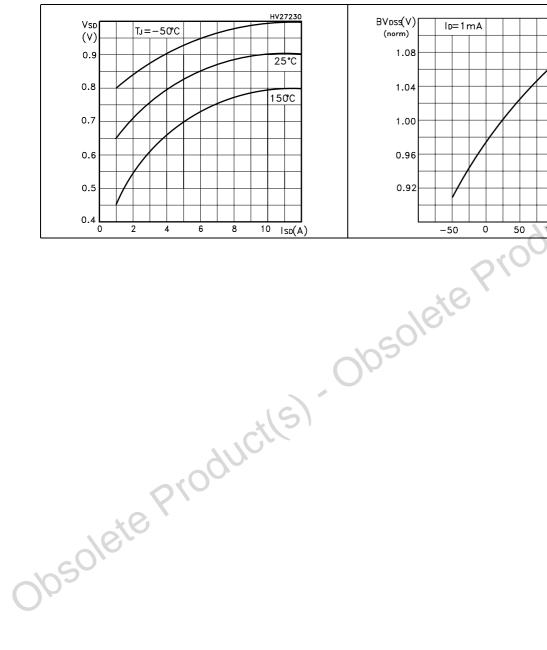
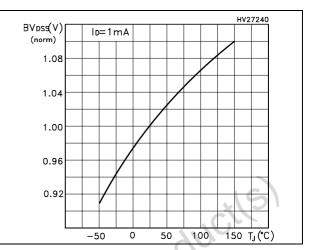


Figure 14. Source-drain diode forward characteristics

Figure 15. Normalized B_{VDSS} vs temperature





3 Test circuit

Figure 16. Switching times test circuit for resistive load

Figure 17. Gate charge test circuit

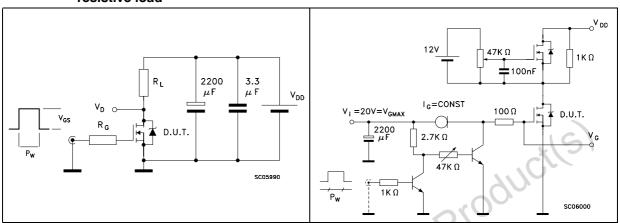


Figure 18. Test circuit for inductive load switching and diode recovery times

Figure 19. Unclamped Inductive load test circuit

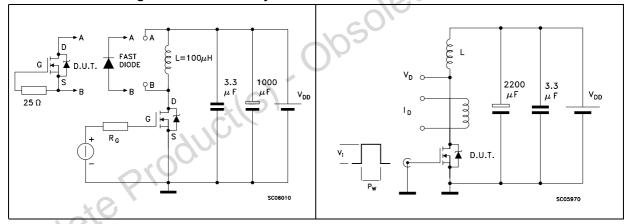
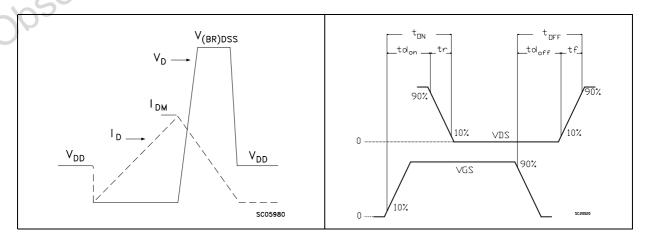


Figure 20. Unclamped inductive waveform

Figure 21. Switching time waveform



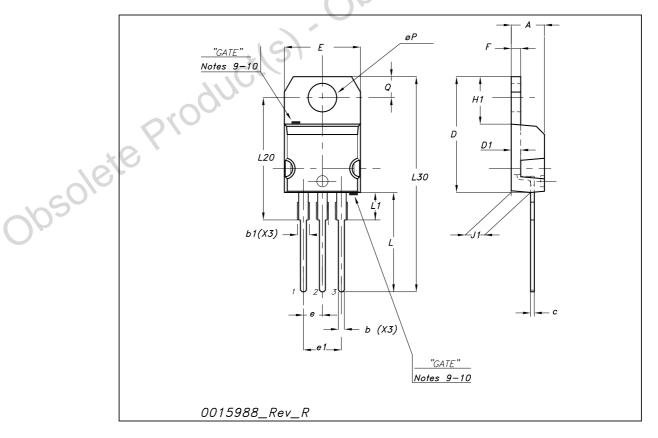
4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

Obsolete Product(s).

TO-220 mechanical data

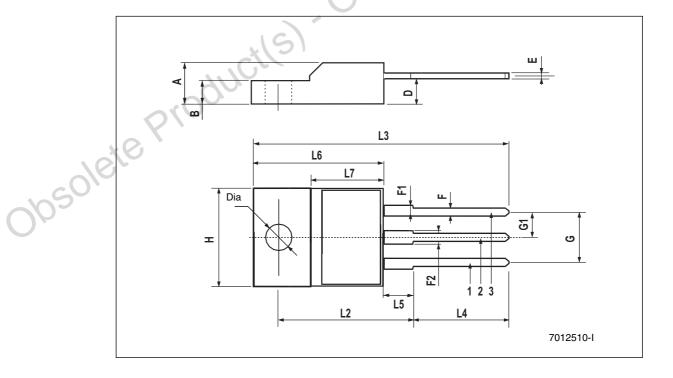
Dim		mm			inch	
Dim	Min	Тур	Max	Min	Тур	Max
A	4.40		4.60	0.173		0.181
b	0.61		0.88	0.024		0.034
b1	1.14		1.70	0.044		0.066
С	0.48		0.70	0.019		0.027
D	15.25		15.75	0.6		0.62
D1		1.27			0.050	
E	10		10.40	0.393		0.409
е	2.40		2.70	0.094		0.106
e1	4.95		5.15	0.194	1110	0.202
F	1.23		1.32	0.048	90	0.051
H1	6.20		6.60	0.244	70.	0.256
J1	2.40		2.72	0.094		0.107
L	13		14	0.511		0.551
L1	3.50		3.93	0.137		0.154
L20		16.40	10.		0.645	
L30		28.90			1.137	
ØP	3.75		3.85	0.147		0.151
Q	2.65		2.95	0.104		0.116



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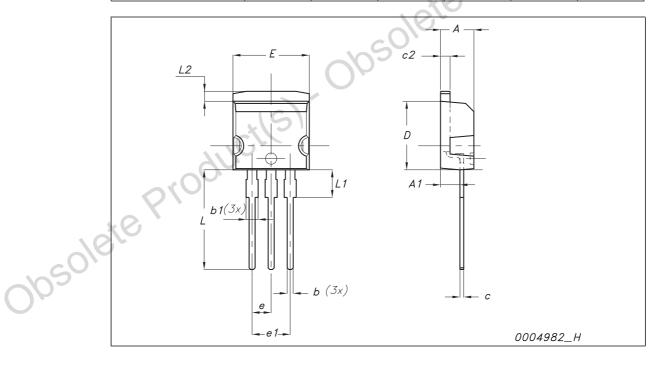
TO-220FP mechanical data

Dim.		mm.			inch	
טוווו.	Min.	Тур	Max.	Min.	Тур.	Max.
Α	4.40		4.60	0.173		0.181
В	2.5		2.7	0.098		0.106
D	2.5		2.75	0.098		0.108
E	0.45		0.70	0.017		0.027
F	0.75		1.00	0.030		0.039
F1	1.15		1.50	0.045		0.067
F2	1.15		1.50	0.045		0.067
G	4.95		5.20	0.195		0.204
G1	2.40		2.70	0.094	. (0.106
Н	10		10.40	0.393	11)	0.409
L2		16			0.630	
L3	28.6		30.6	1.126		1.204
L4	9.80		10.60	0.385		0.417
L5	2.9		3.6	0.114		0.141
L6	15.90		16.40	0.626		0.645
L7	9		9.30	0.354		0.366
Dia	3		3.2	0.118		0.126



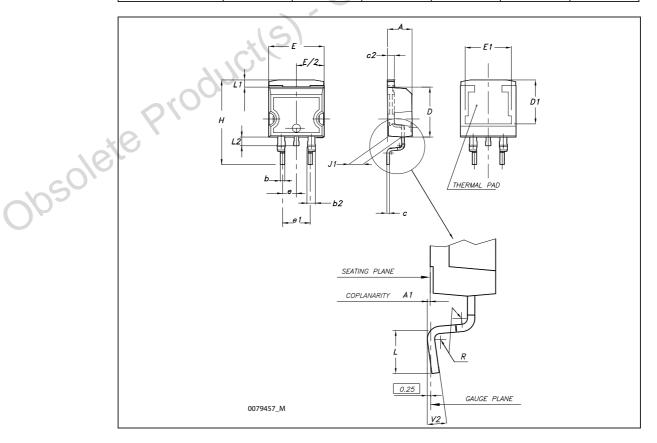
I²PAK (TO-262) mechanical data

Dim		mm			inch	
Dilli	Min	Тур	Max	Min	Тур	Max
А	4.40		4.60	0.173		0.181
A1	2.40		2.72	0.094		0.107
b	0.61		0.88	0.024		0.034
b1	1.14		1.70	0.044		0.066
С	0.49		0.70	0.019		0.027
c2	1.23		1.32	0.048		0.052
D	8.95		9.35	0.352	X	0.368
е	2.40		2.70	0.094	, C	0.106
e1	4.95		5.15	0.194	717	0.202
E	10		10.40	0.393	70)	0.410
L	13		14	0.511		0.551
L1	3.50		3.93	0.137		0.154
L2	1.27		1.40	0.050		0.055



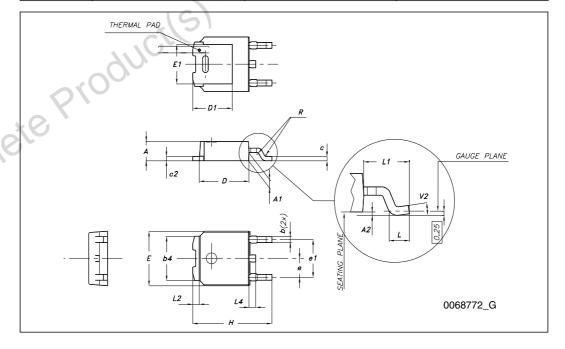
D²PAK (TO-263) mechanical data

Dim		mm			inch	
Dilli	Min	Тур	Max	Min	Тур	Max
Α	4.40		4.60	0.173		0.181
A1	0.03		0.23	0.001		0.009
b	0.70		0.93	0.027		0.037
b2	1.14		1.70	0.045		0.067
С	0.45		0.60	0.017		0.024
c2	1.23		1.36	0.048		0.053
D	8.95		9.35	0.352	4	0.368
D1	7.50			0.295	. C	
Е	10		10.40	0.394	1116	0.409
E1	8.50			0.334	~O.o.	
е		2.54		24	0.1	
e1	4.88		5.28	0.192		0.208
Н	15		15.85	0.590		0.624
J1	2.49		2.69	0.099		0.106
L	2.29		2.79	0.090		0.110
L1	1.27		1.40	0.05		0.055
L2	1.30		1.75	0.051		0.069
R		0.4			0.016	
V2	0°		8°	0°		8°



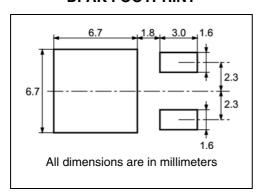
TO-252 (DPAK) mechanical data

DIM.	mm.		
	min.	typ	max.
Α	2.20		2.40
A1	0.90		1.10
A2	0.03		0.23
b	0.64		0.90
b4	5.20		5.40
С	0.45		0.60
c2	0.48		0.60
D	6.00		6.20
D1		5.10	(0)
E	6.40		6.60
E1		4.70	70,
е		2.28	
e1	4.40		4.60
Н	9.35	201	10.10
L	1	10.	
L1		2.80	
L2		0.80	
L4	0.60	700	1
R		0.20	
V2	0 °		8 °

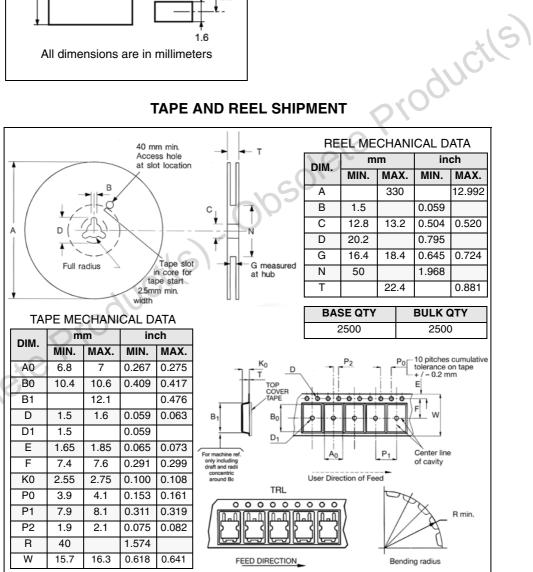


5 Packaging mechanical data

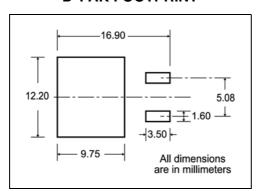
DPAK FOOTPRINT



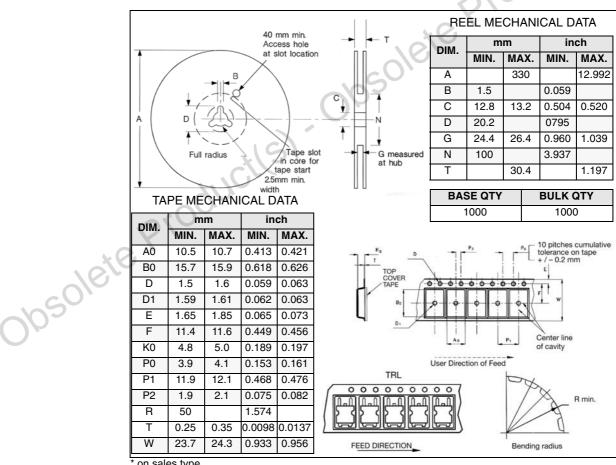
TAPE AND REEL SHIPMENT



D²PAK FOOTPRINT



TAPE AND REEL SHIPMENT



on sales type

6 Revision history

Table 9. Document revision history

Date	Date Revis	on Changes
24-May-2005	24-May-2005 1	Initial release
10-Jun-2005	10-Jun-2005 2	Inserted new row in Table 7.: Switching times
28-Sep-2005	28-Sep-2005 3	Document status promoted from preliminary data to datasheet.
14-Oct-2005	14-Oct-2005 4	Modified Figure 6, Figure 9
06-Mar-2006	06-Mar-2006 5	Modified Figure 8
29-Mar-2006	29-Mar-2006 6	Modified value on <i>Table 5</i> .
14-Nov-2006	14-Nov-2006 7	Document reformatted no content change
24-Jul-2008	24-Jul-2008 8	 Added I²PAK; Table 3: Thermal data has been updated; Figure 11: Capacitance variations changed.
Prod	olete Product	5)

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